



MMBT2222A

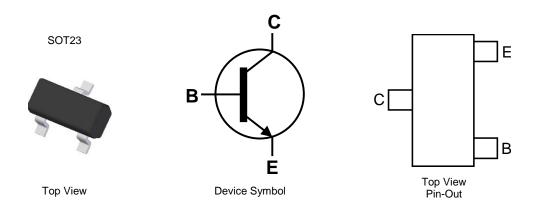
40V NPN SMALL SIGNAL TRANSISTOR IN SOT23

Features

- **Epitaxial Planar Die Construction**
- Complementary PNP Type: MMBT2907A
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 @3)
- Weight: 0.008 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
MMBT2222A-7-F	Active	AEC-Q101	K1P	7	8	3,000
MMBT2222A-13-F	Active	AEC-Q101	K1P	13	8	10,000
MMBT2222AQ-7-F	Active	Automotive	K1P	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

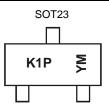
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



K1P = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M or \overline{M} = Month (ex: 9 = September)

Date Code Key												
Year	201	5 2	016	2017	2018	2019	2020	202	1 2	022	2023	2024
Code	С		D	E	F	G	Н			J	К	L
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	75	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current	lc	600	mA
Peak Collector Current	I _{CM}	800	mA
Peak Base Current	I _{BM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Collector Power Dissipation	(Note 6)	D	310	mW	
Collector Power Dissipation	(Note 7)	PD	350	mvv	
Thermal Desistance, lunction to Ambient	(Note 6)	P	403	80 M/	
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	357	°C/W	
Thermal Resistance, Junction to Leads	(Note 8)	R _{θJL}	350	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

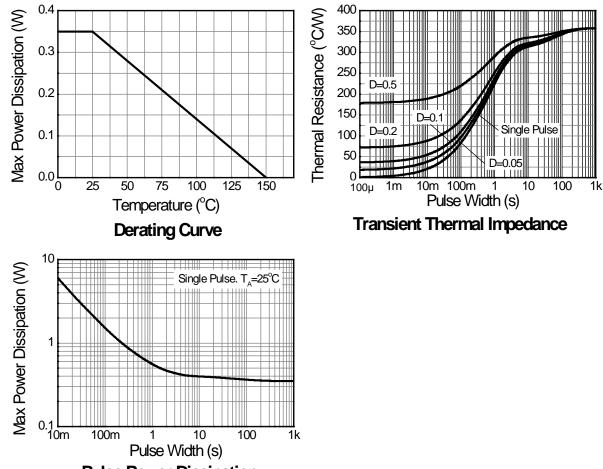
6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state.

7. Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.

Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS				•	-
Collector-Base Breakdown Voltage	BVCBO	75	_	V	$I_{C} = 100 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	40	_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BVEBO	6.0	_	V	$I_{\rm E} = 100 \mu A, I_{\rm C} = 0$
Collector Cut-Off Current	I _{CBO}	_	10	nA μA	$V_{CB} = 60V, I_E = 0$ $V_{CB} = 60V, I_E = 0, T_A = +150^{\circ}C$
Collector Cut-Off Current	ICEX	_	10	nA	$V_{CE} = 60V, V_{EB(OFF)} = 3.0V$
Collector Cut-Off Current	ICEV	_	10	nA	$V_{CE} = 60V, V_{BE} = \pm 0.25V$
Emitter Cut-Off Current	I _{EBO}	_	10	nA	$V_{EB} = 5.0V, I_C = 0$
Base Cut-Off Current	I _{BL}	_	20	nA	$V_{CE} = 60V, V_{EB(OFF)} = 3.0V$
ON CHARACTERISTICS (Note 10)					·
DC Current Gain	h _{FE}	35 50 75 100 40 50 35	 300 	_	$\begin{split} I_{C} &= 100 \mu A, V_{CE} = 10V\\ I_{C} &= 1.0 m A, V_{CE} = 10V\\ I_{C} &= 10 m A, V_{CE} = 10V\\ I_{C} &= 150 m A, V_{CE} = 10V\\ I_{C} &= 500 m A, V_{CE} = 10V\\ I_{C} &= 10 m A, V_{CE} = 10V, T_{A} = -55^{\circ}C\\ I_{C} &= 150 m A, V_{CE} = 1.0V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	0.3 1.0	V	$I_{C} = 150$ mA, $I_{B} = 15$ mA $I_{C} = 500$ mA, $I_{B} = 50$ mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	0.6	1.2 2.0	V	$I_{C} = 150$ mA, $I_{B} = 15$ mA $I_{C} = 500$ mA, $I_{B} = 50$ mA
SMALL SIGNAL CHARACTERISTICS					·
Output Capacitance	Cobo	_	8	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$
Input Capacitance	C _{ibo}	_	25	pF	V _{EB} = 0.5V, f = 1.0MHz, I _C = 0
Current Gain-Bandwidth Product	f⊤	300	_	MHz	$V_{CE} = 20V, I_C = 20mA,$ f = 100MHz
Noise Figure	N _F	_	4.0	dB	$V_{CE} = 10V, I_C = 100\mu A,$ $R_S = 1.0k\Omega, f = 1.0kHz$
SWITCHING CHARACTERISTICS					·
Delay Time	t _D	_	10	ns	$V_{CC} = 30V, I_C = 150mA,$ $V_{BE(OFF)} = -0.5V, I_{B1} = 15mA$
Rise Time	t _R		25	ns	$\label{eq:VCC} \begin{array}{l} V_{CC}=3.0 \text{V}, \ I_{C}=150 \text{mA}, \ I_{B1}=15 \text{mA}, \\ V_{BE(OFF)}=0.5 \text{V} \end{array}$
Storage Time	ts	_	225	ns	$V_{CC} = 30V, I_C = 150mA,$ $I_{B1} = I_{B2} = 15mA$
Fall Time	t _F		60	ns	V _{CC} = 30V, I _C = 150mA, I _{B1} = I _{B2} = 15mA

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



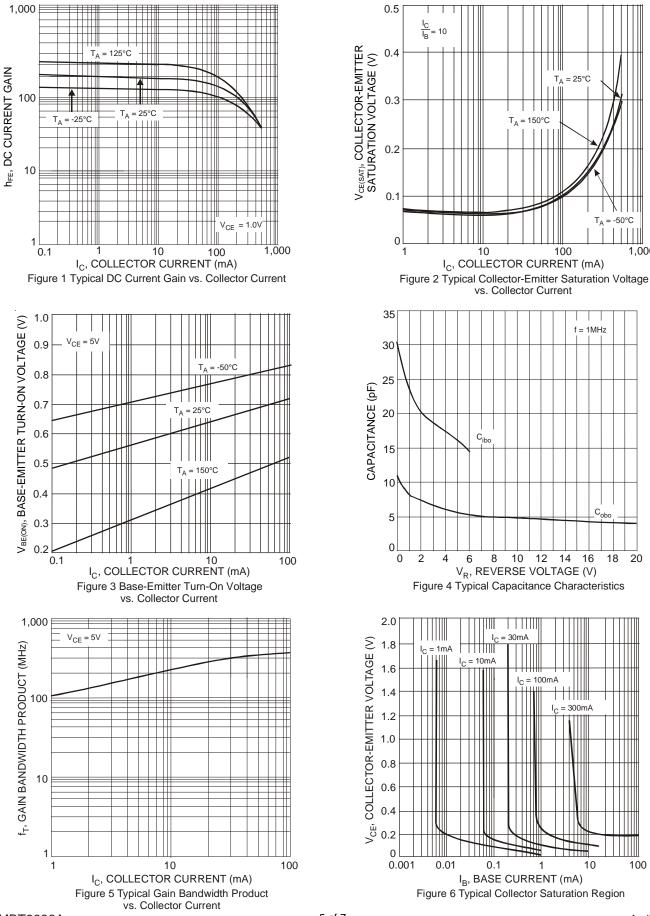


 $T_A = -50^{\circ}C$

C_{obo}

18 20

1,000



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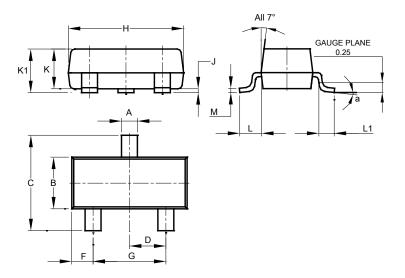
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

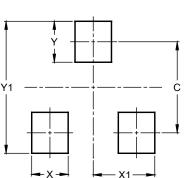
SOT23



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
Н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
К	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	0°	8°							
All	Dimens	ions in	mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23



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